NSN 5962-01-435-5813

Digital Microcircuit - Page 1 of 1



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Maximum Power Dissipation Rating:

500.0 milliwatts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

End Application:

C-17a acft

Features Provided:

3-state output

Inclosure Configuration:

Leaded chip carrier

Output Logic Form:

Bipolar metal-oxide semiconductor

Design Function And Quantity:

8 buffer, tri-state and 8 driver

Current Rating Per Characteristic:

96.00 milliamperes peak forward surge current horsepower metric

Product Name:

Microcircuit, digital, advanced bipolar cmos, octal buffer/driver with three-state outputs, ttl compatible inputs, monolithic silicon

Voltage Rating And Type Per Characteristic:

5.0 volts power source

Special Features:

Ttl compatiable inputs, advanced bicmos

Terminal Type And Quantity:

20 pin

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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